







LM117, LM317-N

SNVS774P - MAY 2004 - REVISED OCTOBER 2015

# LM117, LM317-N Wide Temperature Three-Pin Adjustable Regulator

#### 1 Features

Texas

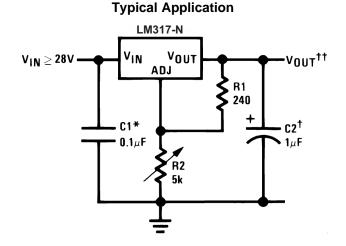
Typ. 0.1% Load Regulation

INSTRUMENTS

- Typ. 0.01%/V Line Regulation
- 1.5-A Output Current
- Adjustable Output Down to 1.25 V
- **Current Limit Constant With Temperature**
- 80-dB Ripple Rejection
- Short-Circuit Protected Output
- -55°C to 150°C Operating Temperature Range (LM117)

# 2 Applications

- Automotive LED Lighting
- **Battery Chargers**
- Post Regulation for Switching Supplies
- **Constant Current Regulators**
- **Microprocessor Supplies**



\*Needed if device is more than 6 inches from filter capacitors.

+Optional—improves transient response

$$_{\dagger\dagger} V_{OUT} = 1.25 V \left( 1 + \frac{R^2}{R^1} \right) + I_{ADJ} \left( R_2 \right)$$

# 3 Description

The LM117 and LM317-N series of adjustable 3-pin positive voltage regulators are capable of supplying in excess of 1.5 A over a 1.25-V to 37-V output range a wide temperature range. They are and exceptionally easy to use and require only two external resistors to set the output voltage. Further, both line and load regulation are better than standard fixed regulators.

The LM117 and LM317-N offer full overload protection such as current limit, thermal overload protection and safe area protection. All overload protection circuitry remains fully functional even if the adjustment terminal is disconnected.

Typically, no capacitors are needed unless the device is situated more than 6 inches from the input filter capacitors, in which case an input bypass is needed. An optional output capacitor can be added to improve transient response. The adjustment terminal can be bypassed to achieve very high ripple rejection ratios that are difficult to achieve with standard 3-terminal regulators.

Because the regulator is *floating* and detects only the input-to-output differential voltage, supplies of several hundred volts can be regulated as long as the maximum input-to-output differential is not exceeded. That is, avoid short-circuiting the output.

connecting a fixed resistor between the Bv adjustment pin and output, the LM117 and LM317-N can be also used as a precision current regulator. Supplies with electronic shutdown can be achieved by clamping the adjustment terminal to ground, which programs the output to 1.25 V where most loads draw little current.

For applications requiring greater output current, see data sheets for LM150 series (3 A), SNVS772, and LM138 series (5 A), SNVS771. For the negative complement, see LM137 (SNVS778) series data sheet.

Device Information <sup>(1)</sup>				
PART NUMBER	PACKAGE	BODY SIZE (NOM)		
I M117	TO-3 (2)	38.94 mm x 25.40 mm		
	TO (3)	8.255 mm × 8.255 mm		
	TO-3 (2)	38.94 mm x 25.40 mm		
	TO-220 (3)	14.986 mm × 10.16 mm		
LM317-N	TO-263 (3)	10.18 mm × 8.41 mm		
	SOT-223 (4)	6.50 mm × 3.50 mm		
	TO (3)	8.255 mm × 8.255 mm		
	TO-252 (3)	6.58 mm × 6.10 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	hanges from Revision O (January 2014) to Revision P	Page
•	Added, updated, or renamed the following sections: Description; Pin Configuration and Functions; Specifications; ESD Ratings table; Application and Implementation; Power Supply Recommendations; Layout, Mechanical, Packaging, and Ordering Information	1
•	Removed information regarding LM317A, formerly part of this data sheet. LM317A can now be found in the TI catalog under literature number SNVSAC2	1
C	hanges from Revision N (August 2013) to Revision O	Page

•	Deleted MDT Package (over Full Operating Temperature Range)	7
•	Changed Current Limit MIN from 0.112 to 0.15 and TYP from 0.3 to 0.4 for (VIN – VOUT) = 40 V in the LM317A and LM317-N Electrical Characteristics Section	7
•	Deleted MDT Package	7

Product Folder Links: LM117 LM317-N

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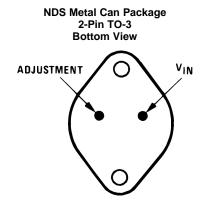


# 5 Device Comparison Table

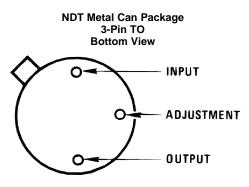
PART NUMBER	TEMPERATURE	DESCRIPTION	PRODUCT FOLDER
LM317-N	0°C to 125°C	40-V, 1.5-A Catalog device	Click here
LM317A	-40°C to 125°C	40-V, 1.5-A Industrial device	Click here
LM317HV	0°C to 125°C	60-V, 1.5-A Catalog device	Click here
LM317L-N	-40°C to 125°C	40-V, 0.1-A, Industrial device	Click here
LM117	-55°C to 150°C	40-V, 1.5-A Extended-temperature device	Click here
LM117HV	-55°C to 150°C	60-V, 1.5-A Extended-temperature device	Click here
LM117HVQML	-55°C to 125°C	60-V, 1.5-A Military-grade device per spec MIL-PRF-38535	Click here
LM117HVQML-SP	-55°C to 125°C	60-V, 1.5-A Space-grade device	Click here
LM117JAN	-55°C to 125°C	40-V, 1.5-A Military-grade device per spec MIL-PRF-38510	Click here
LM117QML	-55°C to 125°C	40-V, 1.5-A Military-grade device per spec MIL-PRF-38535	Click here
LM117QML-SP	-55°C to 125°C	40-V, 1.5-A Space-grade device	Click here

# Table 1. LM317 Family Options

# 6 Pin Configuration and Functions



Case is Output

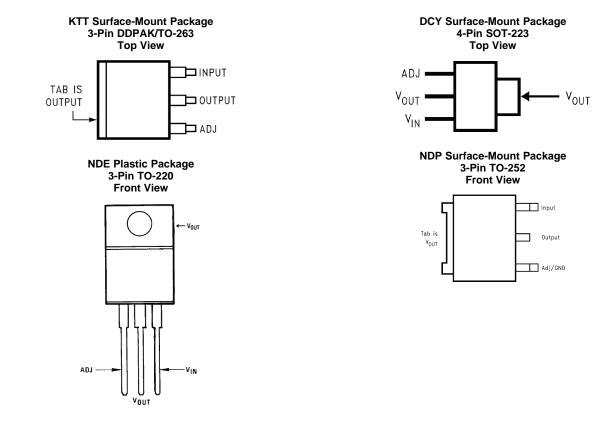


Case is Output

## Pin Functions, Metal Can Packages

	PIN		1/0	DESCRIPTION	
NAME	TO-3	то	I/O	DESCRIPTION	
ADJ	1	2	— Adjust pin		
V <sub>OUT</sub>	CASE	3, CASE	O Output voltage pin for the regulator		
V <sub>IN</sub>	2	1	I	Input voltage pin for the regulator	





# **Pin Functions**

	PIN				1/0	DESCRIPTION	
NAME	TO-263	TO-220	SOT-223	TO-252	I/O	DESCRIPTION	
ADJ	1	1	1	1	—	Adjust pin	
V <sub>OUT</sub>	2, TAB	2, TAB	2, 4	2, TAB	0	Output voltage pin for the regulator	
V <sub>IN</sub>	3	3	3	3	I	Input voltage pin for the regulator	

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# 7 Specifications

# 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)(2)</sup>

		MIN	MAX	UNIT
Power dissipation	ation Internally Limited			
Input-output voltage differ	rential	-0.3	-0.3 40	
	Metal package (soldering, 10 seconds)		300	°C
Lead temperature	Plastic package (soldering, 4 seconds)		260	°C
Storage temperature, T <sub>sto</sub>		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.

# 7.2 ESD Ratings

		VALUE	UNIT
V <sub>(ESD)</sub> Electrostatic discharge	Human-body model (HBM) <sup>(1)</sup>	±3000	V

(1) Manufacturing with less than 500-V HBM is possible with the necessary precautions. Pins listed as ±3000 V may actually have higher performance.

# 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Operating temperature (LM117)	-55	150	°C
Operating temperature (LM317-N)	0	125	°C

# 7.4 Thermal Information, LM117

		LM1		
	THERMAL METRIC <sup>(1)</sup>	NDS (TO-3)	NDT (TO)	UNIT
		2 PINS	3 PINS	
$R_{\thetaJA}$	Junction-to-ambient thermal resistance <sup>(2)</sup>	39	186	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	2	21	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

(2) No heatsink.

# LM117, LM317-N

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#### IEXAS INSTRUMENTS

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# 7.5 Thermal Information, LM317-N

			LM317-N					
	THERMAL METRIC <sup>(1)(2)</sup>	KTT (TO-263)	NDE (TO-220)	DCY (SOT-223)	NDT (TO)	NDP (TO-252)	UNIT	
		3 PINS	3 PINS	4 PINS	3 PINS	3 PINS		
R <sub>0JA</sub>	Junction-to-ambient thermal resistance	41.0	23.3	59.6	186 <sup>(3)</sup>	54	°C/W	
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	43.6	16.2	39.3	21	51.3	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	23.6	4.9	8.4	—	28.6	°C/W	
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	10.4	2.7	1.8	—	3.9	°C/W	
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	22.6	4.9	8.3	_	28.1	°C/W	
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	0.9	1.1	—	—	0.9	°C/W	

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

(2) When surface mount packages are used (SOT-223, TO-252), the junction to ambient thermal resistance can be reduced by increasing

the PCB copper area that is thermally connected to the package. See Heatsink Requirements for heatsink techniques.

(3) No heatsink

# 7.6 LM117 Electrical Characteristics

Some specifications apply over full Operating Temperature Range as noted. Unless otherwise specified,  $T_J = 25^{\circ}C$ ,  $V_{IN} - V_{OUT} = 5 \text{ V}$ , and  $I_{OUT} = 10 \text{ mA.}^{(1)(2)}$ 

PARAMETER	TEST CC	MIN	TYP	MAX	UNIT	
Reference voltage	$\begin{array}{l} 3 \text{ V} \leq (\text{V}_{\text{IN}} - \text{V}_{\text{OUT}}) \leq 40 \text{ V}, \\ 10 \text{ mA} \leq \text{I}_{\text{OUT}} \leq \text{I}_{\text{MAX}}^{(1)} \text{ (over full} \end{array}$	1.2	1.25	1.3	V	
		$T_J = 25^{\circ}C$		0.01	0.02	
Line regulation	$3 V \le (V_{IN} - V_{OUT}) \le 40 V^{(3)}$	over full operating temperature range		0.02	0.05	%/V
		$T_J = 25^{\circ}C$		0.1%	0.3%	
Load regulation	$10 \text{ mA} \le I_{OUT} \le I_{MAX}^{(1)(3)}$	over full operating temperature range		0.3%	1%	
Thermal regulation	20-ms pulse			0.03	0.07	%/W
Adjustment pin current	over full operating temperature r	ange		50	100	μA
Adjustment pin current change	$\begin{array}{c} 10 \text{ mA} \leq I_{\text{OUT}} \leq I_{\text{MAX}}^{(1)} \\ 3 \text{ V} \leq (\text{V}_{\text{IN}} - \text{V}_{\text{OUT}}) \leq 40 \text{ V} \text{ (over } \end{array}$		0.2	5	μA	
Temperature stability	$T_{MIN} \le T_J \le TMAX$ (over full open		1%			
Minimum load current	$(V_{IN} - V_{OUT}) = 40 \text{ V}$ (over full op		3.5	5	mA	
		TO-3 Package (over full operating temperature range)	1.5	2.2	3.4	٨
Current limit	(V <sub>IN</sub> − V <sub>OUT</sub> ) ≤ 15 V	TO-39 Package (over full operating temperature range)	0.5	0.8	1.8	A
		TO-3 package	0.3	0.4		٨
	$(V_{IN} - V_{OUT}) = 40 V$	0.15	0.2		A	
RMS output noise, % of $V_{OUT}$	10 Hz ≤ f ≤ 10 kHz			0.003%		
<b>S</b> i i i i i	$V_{OUT} = 10 V$ , f = 120 Hz, $C_{ADJ} = temperature range)$		65		dB	
Ripple rejection ratio	$V_{OUT}$ = 10 V, f = 120 Hz, $C_{ADJ}$ = temperature range)	66	80		dB	
Long-term stability	T <sub>J</sub> = 125°C, 1000 hrs		0.3%	1%		

 I<sub>MAX</sub> = 1.5 A for the NDS (TO-3), NDE (TO-220), and KTT (TO-263) packages. I<sub>MAX</sub> = 1.0 A for the DCY (SOT-223) package. I<sub>MAX</sub> = 0.5 A for the NDT (TO) and NDP (TO-252) packages. Device power dissipation (P<sub>D</sub>) is limited by ambient temperature (T<sub>A</sub>), device maximum junction temperature (T<sub>J</sub>), and package thermal resistance (θ<sub>JA</sub>). The maximum allowable power dissipation at any temperature is : P<sub>D(MAX)</sub> = ((T<sub>J(MAX)</sub> - T<sub>A</sub>) / θ<sub>JA</sub>). All Min. and Max. limits are ensured to TI's Average Outgoing Quality Level (AOQL).
(2) Specifications and availability for military and space grades of LM117/883 can be found in the LM117QML data sheet (SNVS356).

Specifications and availability for military and space grades of LM117 can be found in the LM117JAN data sheet (SNVS365).

(3) Regulation is measured at a constant junction temperature, using pulse testing with a low duty cycle. Changes in output voltage due to heating effects are covered under the specifications for thermal regulation.



# 7.7 LM317-N Electrical Characteristics<sup>(1)</sup>

Some specifications apply over full Operating Temperature Range as noted. Unless otherwise specified, T<sub>J</sub> = 25°C, V<sub>IN</sub> - $V_{OUT} = 5 V$ , and  $I_{OUT} = 10 mA$ .

PARAMETER	TEST CO	TEST CONDITIONS				
	$T_J = 25^{\circ}C$		1.25		V	
Reference voltage	$\begin{array}{l} 3 \hspace{0.1cm} V \leq (V_{IN} - V_{OUT}) \leq 40 \hspace{0.1cm} V, \\ 10 \hspace{0.1cm} \text{mA} \leq I_{OUT} \leq I_{MAX} ^{(1)} \hspace{0.1cm} (\text{over Fit} \\ \text{Range}) \end{array}$	1.2	1.25	1.3	V	
		$T_J = 25^{\circ}C$		0.01	0.04	
Line regulation	$3V \le (V_{\rm IN} - V_{\rm OUT}) \le 40 \ V^{(2)}$	(over full operating temperature range)		0.02	0.07	%/V
		$T_J = 25^{\circ}C$		0.1%	0.5%	
Load regulation	$10 \text{ mA} \leq I_{OUT} \leq I_{MAX}^{(1)(2)}$	(over full operating temperature range)		0.3%	1.5%	
Thermal regulation	20-ms pulse			0.04	0.07	%/W
Adjustment pin current	(over full operating temperature	e range)		50	100	μA
Adjustment pin current change	$\begin{array}{l} 10 \text{ mA} \leq I_{\text{OUT}} \leq I_{\text{MAX}}^{(1)} \\ 3V \leq (V_{\text{IN}} - V_{\text{OUT}}) \leq 40V \end{array}$	(over full operating temperature range)		0.2	5	μA
Temperature stability	$T_{MIN} \leq T_{J} \leq T_{MAX}$		1%			
Minimum load current	(V <sub>IN</sub> - V <sub>OUT</sub> ) = 40 V	$(V_{IN} - V_{OUT}) = 40 \text{ V}$ (over full operating temperature range)				mA
		TO-3, TO-263 Packages (over full operating temperature range)	1.5	2.2	3.4	
Current limit	$(V_{\rm IN} - V_{\rm OUT}) \le 15 \ V$	SOT-223, TO-220 Packages (over full operating temperature range)	1.5	2.2	3.4	A
Current limit		TO, TO-252 Package (over full operating temperature range)	0.5	0.8	1.8	
		TO-3, TO-263 packages	0.15	0.4		
	$(V_{IN} - V_{OUT}) = 40 V$	SOT-223, TO-220 packages	0.15	0.4		А
		TO, TO-252 package	0.075	0.2		
RMS output noise, % of $\mathrm{V}_{\mathrm{OUT}}$	10 Hz ≤ f ≤ 10 kHz			0.003%		
	$V_{OUT} = 10 V$ , f = 120 Hz, $C_{ADJ}$ temperature range)		65		dB	
Ripple rejection ratio	$V_{OUT}$ = 10V, f = 120 Hz, $C_{ADJ}$ : temperature range)	66	80		dB	
Long-term stability	T <sub>J</sub> = 125°C, 1000 hrs			0.3%	1%	

(1)  $I_{MAX} = 1.5$  A for the NDS (TO-3), NDE (TO-220), and KTT (TO-263) packages.  $I_{MAX} = 1.0$  A for the DCY (SOT-223) package. I<sub>MAX</sub> = 0.5 A for the NDT (TO) and NDP (TO-252) packages. Device power dissipation (P<sub>D</sub>) is limited by ambient temperature (T<sub>A</sub>), device maximum junction temperature (T<sub>J</sub>), and package thermal resistance ( $\theta_{JA}$ ). The maximum allowable power dissipation at any temperature is :  $P_{D(MAX)} = ((T_{J(MAX)} - T_A) / \theta_{JA})$ . All Min. and Max. limits are ensured to TI's Average Outgoing Quality Level (AOQL). (2) Regulation is measured at a constant junction temperature, using pulse testing with a low duty cycle. Changes in output voltage due to

heating effects are covered under the specifications for thermal regulation.

LM117, LM317-N

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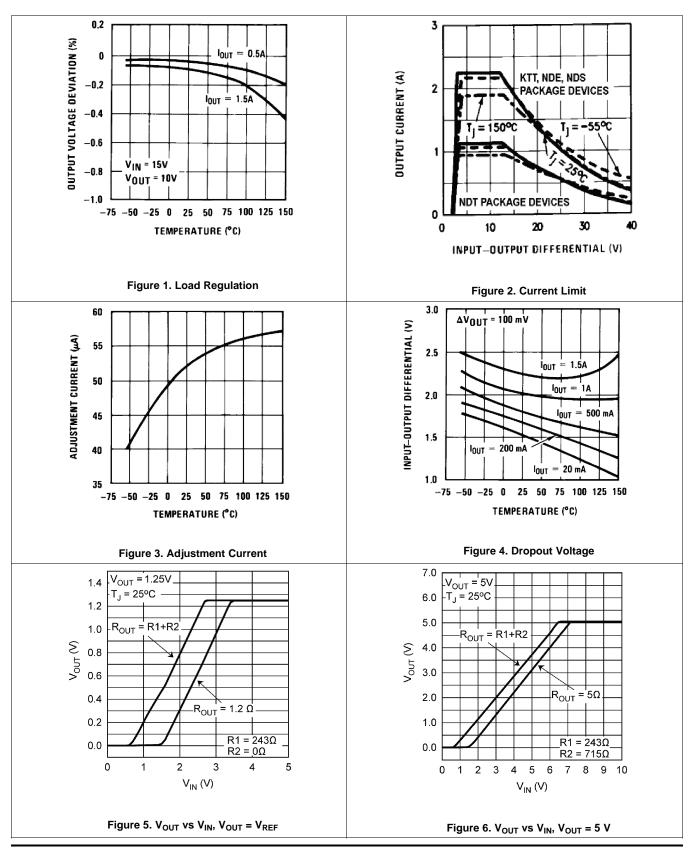
INSTRUMENTS

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EXAS

7.8 Typical Characteristics

Output Capacitor = 0 µF, unless otherwise noted.



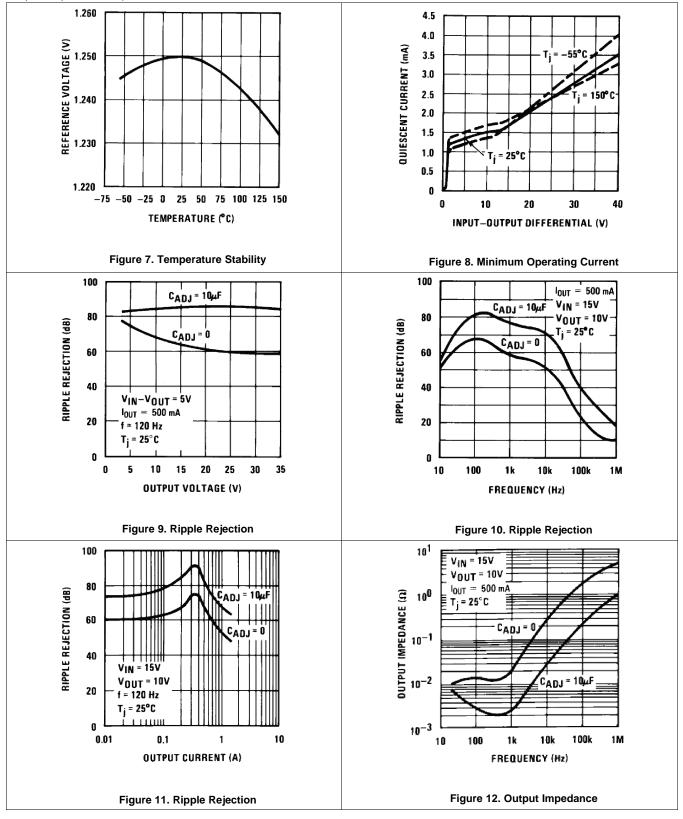
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# **Typical Characteristics (continued)**

Output Capacitor = 0  $\mu$ F, unless otherwise noted.



# LM117, LM317-N

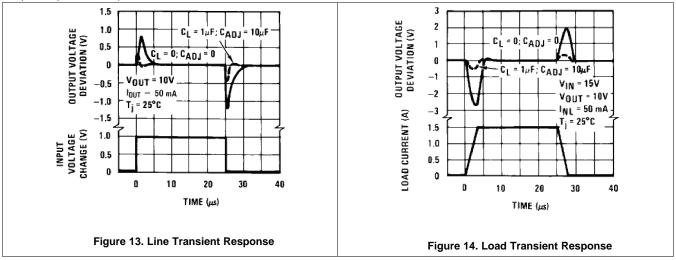
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# **Typical Characteristics (continued)**

Output Capacitor = 0 µF, unless otherwise noted.





# 8 Detailed Description

#### 8.1 Overview

In operation, the LM317-N develops a nominal 1.25-V reference voltage,  $V_{REF}$ , between the output and adjustment terminal. The reference voltage is impressed across program resistor R1 and, because the voltage is constant, a constant current  $I_1$  then flows through the output set resistor R2, giving an output voltage calculated by Equation 1:

$$V_{OUT} = 1.25 V \left(1 + \frac{R^2}{R^1}\right) + I_{ADJ} \left(R_2\right)$$

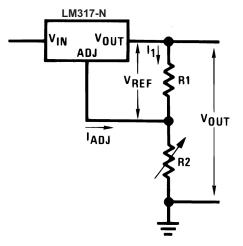


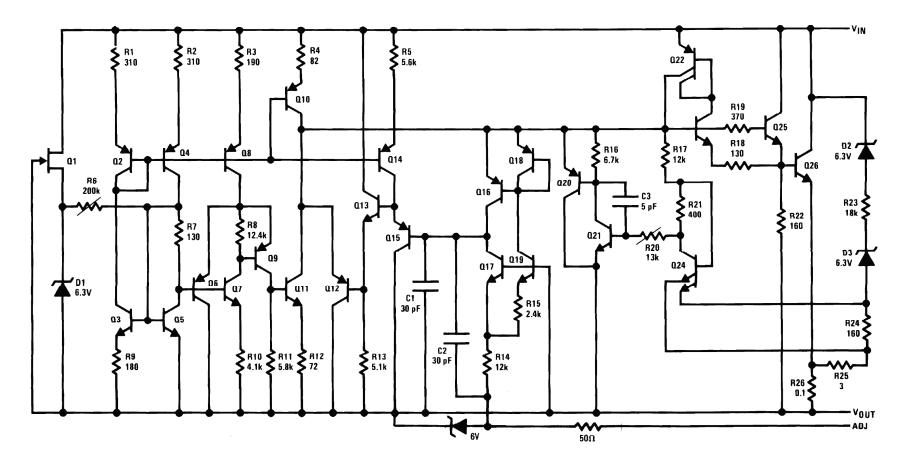
Figure 15. Setting the V<sub>OUT</sub> Voltage

Because the 100- $\mu$ A current from the adjustment terminal represents an error term, the LM317-N was designed to minimize  $I_{ADJ}$  and make it very constant with line and load changes. To do this, all quiescent operating current is returned to the output establishing a minimum load current requirement. If there is insufficient load on the output, the output will rise.

(1)



# 8.2 Functional Block Diagram





#### 8.3 Feature Description

#### 8.3.1 Load Regulation

The LM317-N is capable of providing extremely good load regulation but a few precautions are needed to obtain maximum performance. The current set resistor, R1, must be connected near the output terminal of the regulator rather than near the load. If R1 is placed too far from the output terminal, then the increased trace resistance,  $R_S$ , will cause an error voltage drop in the adjustment loop and degrade load regulation performance. Therefore, R1 must be placed as close as possible to the output terminal to minimize  $R_S$  and maximize load regulation performance.

Figure 16 shows the effect of the trace resistance,  $R_s$ , when R1 is placed far from the output terminal of the regulator. It is clear that  $R_s$  will cause an error voltage drop especially during higher current loads, so it is important to minimize the  $R_s$  trace resistance by keeping R1 close to the regulator output terminal.

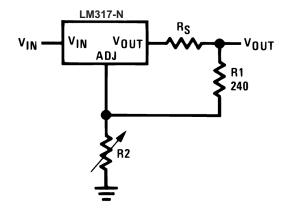


Figure 16. Regulator With Line Resistance in Output Lead

With the TO-3 package, it is easy to minimize the resistance from the case to the set resistor, by using two separate leads to the case. However, with the TO package, care must be taken to minimize the wire length of the output lead. The ground of R2 can be returned near the ground of the load to provide remote ground sensing and improve load regulation.

# 8.4 Device Functional Modes

#### 8.4.1 External Capacitors

An input bypass capacitor is recommended. A  $0.1-\mu F$  disc or  $1-\mu F$  solid tantalum on the input is suitable input bypassing for almost all applications. The device is more sensitive to the absence of input bypassing when adjustment or output capacitors are used, but the above values will eliminate the possibility of problems.

The adjustment terminal can be bypassed to ground on the LM317-N to improve ripple rejection. This bypass capacitor prevents ripple from being amplified as the output voltage is increased. With a 10- $\mu$ F bypass capacitor, 80-dB ripple rejection is obtainable at any output level. Increases over 10  $\mu$ F do not appreciably improve the ripple rejection at frequencies above 120 Hz. If the bypass capacitor is used, it is sometimes necessary to include protection diodes to prevent the capacitor from discharging through internal low current paths and damaging the device.

In general, the best type of capacitors to use is solid tantalum. Solid tantalum capacitors have low impedance even at high frequencies. Depending upon capacitor construction, it takes about 25  $\mu$ F in aluminum electrolytic to equal 1- $\mu$ F solid tantalum at high frequencies. Ceramic capacitors are also good at high frequencies. However, some types have a large decrease in capacitance at frequencies around 0.5 MHz. For this reason, 0.01- $\mu$ F disc may seem to work better than a 0.1- $\mu$ F disc as a bypass.

Although the LM317-N is stable with no output capacitors, like any feedback circuit, certain values of external capacitance can cause excessive ringing. This occurs with values between 500 pF and 5000 pF. A 1- $\mu$ F solid tantalum (or 25- $\mu$ F aluminum electrolytic) on the output swamps this effect and insures stability. Any increase of the load capacitance larger than 10  $\mu$ F will merely improve the loop stability and output impedance.

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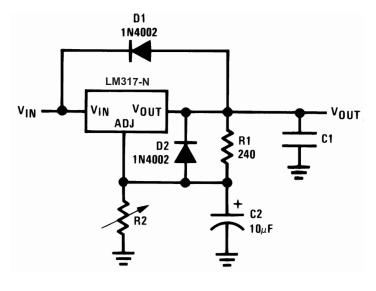
# **Device Functional Modes (continued)**

#### 8.4.2 Protection Diodes

When external capacitors are used with any IC regulator, it is sometimes necessary to add protection diodes to prevent the capacitors from discharging through low current points into the regulator. Most 10-µF capacitors have low enough internal series resistance to deliver 20-A spikes when shorted. Although the surge is short, there is enough energy to damage parts of the IC.

When an output capacitor is connected to a regulator and the input is shorted, the output capacitor will discharge into the output of the regulator. The discharge current depends on the value of the capacitor, the output voltage of the regulator, and the rate of decrease of  $V_{IN}$ . In the LM317-N, this discharge path is through a large junction that is able to sustain 15-A surge with no problem. This is not true of other types of positive regulators. For output capacitors of 25  $\mu$ F or less, there is no need to use diodes.

The bypass capacitor on the adjustment terminal can discharge through a low current junction. Discharge occurs when *either* the input, or the output, is shorted. Internal to the LM317-N is a 50- $\Omega$  resistor which limits the peak discharge current. No protection is needed for output voltages of 25 V or less and 10- $\mu$ F capacitance. Figure 17 shows an LM317-N with protection diodes included for use with outputs greater than 25 V and high values of output capacitance.



$$V_{OUT} = 1.25 V \left(1 + \frac{R^2}{R^1}\right) + I_{ADJ} \left(R_2\right)$$

D1 protects against C1

D2 protects against C2

# Figure 17. Regulator With Protection Diodes



# 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers must validate and test their design implementation to confirm system functionality.

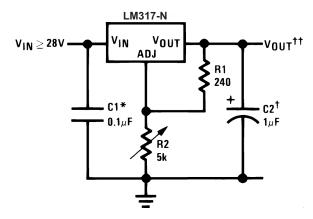
## 9.1 Application Information

The LM117 and LM317-N are versatile, high performance, linear regulators with high accuracy and a wide temperature range. An output capacitor can be added to further improve transient response, and the ADJ pin can be bypassed to achieve very high ripple-rejection ratios. Its functionality can be utilized in many different applications that require high performance regulation, such as battery chargers, constant current regulators, and microprocessor supplies.

## 9.2 Typical Applications

#### 9.2.1 1.25-V to 25-V Adjustable Regulator

The LM117 can be used as a simple, low-dropout regulator to enable a variety of output voltages needed for demanding applications. By using an adjustable R2 resistor, a variety of output voltages can be made possible as shown in Figure 18.

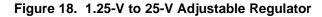


NOTE: Full output current not available at high input-output voltages

\*Needed if device is more than 6 inches from filter capacitors.

 $\dagger$ Optional—improves transient response. Output capacitors in the range of 1  $\mu$ F to 1000  $\mu$ F of aluminum or tantalum electrolytic are commonly used to provide improved output impedance and rejection of transients.

$$\dagger \dagger V_{\text{OUT}} = 1.25V \left(1 + \frac{\text{R2}}{\text{R1}}\right) + I_{\text{ADJ}}(\text{R}_2)$$



#### 9.2.1.1 Design Requirements

The device component count is very minimal, employing two resistors as part of a voltage divider circuit and an output capacitor for load regulation. An input capacitor is needed if the device is more than 6 inches from filter capacitors. An optional bypass capacitor across R2 can also be used to improve PSRR.

#### 9.2.1.2 Detailed Design Procedure

The output voltage is set based on the selection of the two resistors, R1 and R2, as shown in Figure 18. For details on capacitor selection, refer to *External Capacitors*.

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# LM117, LM317-N

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V<sub>out</sub> (V)

As shown in Figure 19, V<sub>OUT</sub> will rise with V<sub>IN</sub> minus some dropout voltage. This dropout voltage during startup will vary with ROUT.



V<sub>IN</sub> (V)

# 9.2.2 5-V Logic Regulator With Electronic Shutdown

VIN 7V-35V

Figure 20 shows a variation of the 5-V output regulator application uses the L117 along with an NPN transistor to provide shutdown control. The NPN will either block or sink the current from the ADJ pin by responding to the TTL pin logic. When TTL is pulled high, the NPN is on and pulls the ADJ pin to GND, and the LM117 outputs about

1.25 V. When TTL is pulled low, the NPN is off and the regulator outputs according to the programmed adjustable voltage.

VOUT

R2

720 2N2219

**R1** 240 V<sub>OUT</sub> 5V

C2

**0.1**µ**F** 

1k

TTL

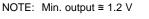
LM317-N

ADJ

VIN

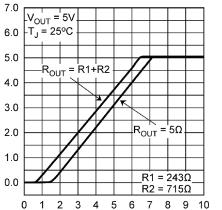
C1

0.1µF



16

Figure 20. 5-V Logic Regulator With Electronic Shutdown





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# **Typical Applications (continued)**

# 9.2.3 Slow Turnon 15-V Regulator

An application of LM117 includes a PNP transistor with a capacitor to implement slow turnon functionality (see Figure 21). As  $V_{IN}$  rises, the PNP sinks current from the ADJ rail. The output voltage at start up is the addition of the 1.25-V reference plus the drop across the base to emitter. While this is happening, the capacitor begins to charge and eventually opens the PNP. At this point, the device functions normally, regulating the output at 15 V. A diode is placed between C1 and  $V_{OUT}$  to provide a path for the capacitor to discharge. Such controlled turnon is useful for limiting the in-rush current.

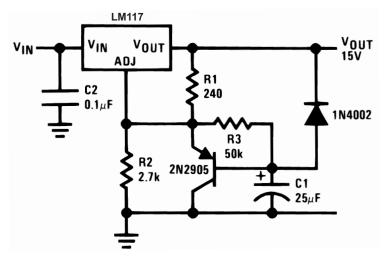
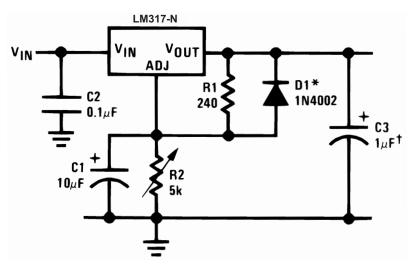


Figure 21. Slow Turnon 15-V Regulator

# **Typical Applications (continued)**

## 9.2.4 Adjustable Regulator With Improved Ripple Rejection

To improve ripple rejection, a capacitor is used to bypass the ADJ pin to GND (see Figure 22). This is used to smooth output ripple by cleaning the feedback path and stopping unnecessary noise from being fed back into the device, propagating the noise.



NOTE: †Solid tantalum

\*Discharges C1 if output is shorted to ground

## Figure 22. Adjustable Regulator With Improved Ripple Rejection

#### 9.2.5 High Stability 10-V Regulator

Using a high stability shunt voltage reference in the feedback path, such as the LM329, provides damping necessary for a stable, low noise output (see Figure 23).

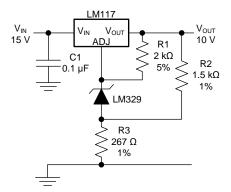


Figure 23. High Stability 10-V Regulator



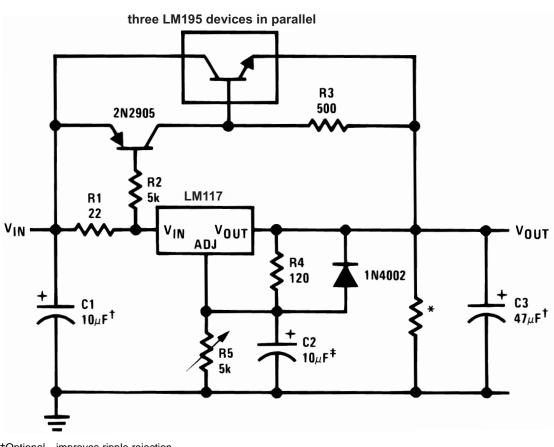
# **Typical Applications (continued)**

#### 9.2.6 High-Current Adjustable Regulator

Using the LM195 power transistor in parallel with the LM117 can increase the maximum possible output load current (see Figure 24). Sense resistor R1 provides the 0.6 V across base to emitter to turn on the PNP. This on switch allows current to flow, and the voltage drop across R3 drives three LM195 power transistors designed to carry an excess of 1 A each.

#### NOTE

The selection of R1 determines a minimum load current for the PNP to turn on. The higher the resistor value, the lower the load current must be before the transistors turn on.



NOTE: ‡Optional—improves ripple rejection †Solid tantalum \*Minimum load current = 30 mA



# **Typical Applications (continued)**

#### 9.2.7 Emitter-Follower Current Amplifier

The LM117 is used as a constant current source in the emitter follower circuit (see Figure 25). The LM195 power transistor is being used as a current gain amplifier, boosting the INPUT current. The LM117 provides a stable current bias than just using a resistor.

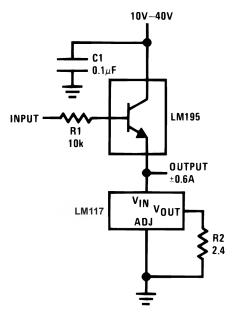


Figure 25. Emitter-Follower Current Amplifier

## 9.2.8 1-A Current Regulator

A simple, fixed current regulator can be made by placing a resistor between the  $V_{OUT}$  and ADJ pins of the LM117 (see Figure 26). By regulating a constant 1.25 V between these two terminals, a constant current is delivered to the load.

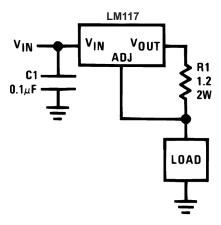


Figure 26. 1-A Current Regulator



# **Typical Applications (continued)**

#### 9.2.9 Common-Emitter Amplifier

Sometimes it is necessary to use a power transistor for high current gain. In this case, the LM117 provides constant current at the collector of the LM195 in this common emitter application (see Figure 27). The 1.25-V reference between  $V_{OUT}$  and ADJ is maintained across the 2.4- $\Omega$  resistor, providing about 500-mA constant bias current into the collector of the LM195.

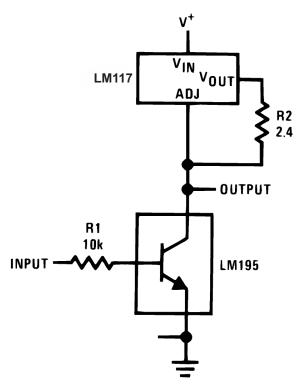
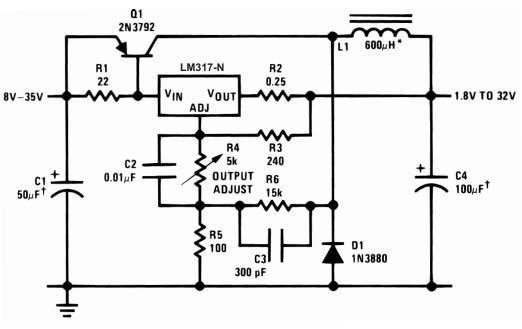


Figure 27. Common-Emitter Amplifier

# **Typical Applications (continued)**

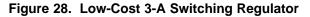
# 9.2.10 Low-Cost 3-A Switching Regulator

The LM317-N can be used in a switching buck regulator application in cost sensitive applications that require high efficiency. The switch node above D1 oscillates between ground and VIN, as the voltage across sense resistor R1 drives the power transistor on and off. Figure 28 exhibits self-oscillating behavior by negative feedback through R6 and C3 to the ADJ pin of the LM317-N.



#### NOTE: †Solid tantalum

\*Core—Arnold A-254168-2 60 turns



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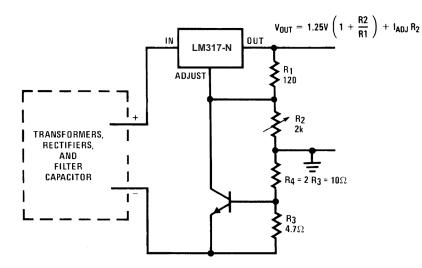
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#### **Typical Applications (continued)**

#### 9.2.11 Current-Limited Voltage Regulator

A maximum limit on output current can be set using the circuit shown in Figure 29. The load current travels through R3 and R4. As the load current increases, the voltage drop across R3 increases until the NPN transistor is driven, during which the ADJ pin is pulled down to ground and the output voltage is pulled down to the reference voltage of 1.25 V.



-Short circuit current is approximately  $\frac{600 \text{ mV}}{R3}$ , or 210 mA

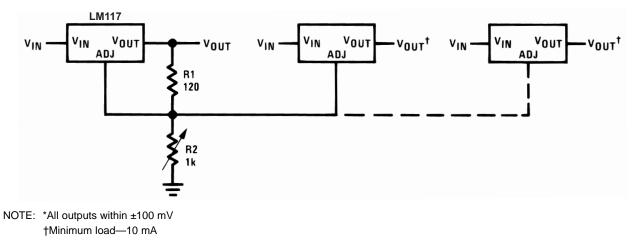
(Compared to LM117's higher current limit)

-At 50 mA output only 34 volt of drop occurs in R3 and R4

# Figure 29. Current-Limited Voltage Regulator

# 9.2.12 Adjusting Multiple On-Card Regulators With Single Control

Figure 30 shows how multiple LM117 regulators can be controlled by setting one resistor. Because each device maintains the reference voltage of about 1.25 V between its  $V_{OUT}$  and ADJ pins, we can connect each ADJ rail to a single resistor, setting the same output voltage across all devices. This allows for independent outputs, each responding to its corresponding input only. Designers must also consider that by the nature of the circuit, changes to R1 and R2 will affect all regulators.







# **Typical Applications (continued)**

## 9.2.13 AC Voltage Regulator

In Figure 31, the top regulator is +6 V above the bottom regulator. It is clear that when the input rises above +6 V plus the dropout voltage, only the top LM317-N regulates +6 V at the output. When the input falls below -6 V minus the dropout voltage, only the bottom LM317-N regulates -6 V at the output. For regions where the output is not clipped, there is no regulation taking place, so the output follows the input.

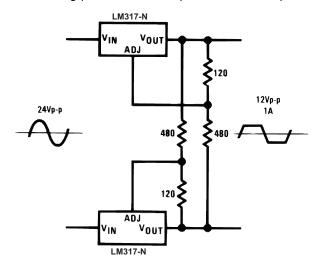
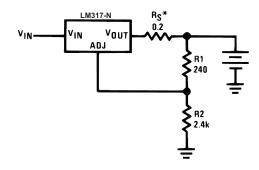


Figure 31. AC Voltage Regulator

## 9.2.14 12-V Battery Charger

The LM317-N can be used in a battery charger application shown in Figure 32, where the device maintains either constant voltage or constant current mode depending on the current charge of the battery. To do this, the part senses the voltage drop across the battery and delivers the maximum charging current necessary to charge the battery. When the battery charge is low, there exists a voltage drop across the sense resistor  $R_S$ , providing constant current to the battery at that instant. As the battery approaches full charge, the potential drop across  $R_S$  approaches zero, reducing the current and maintaining the fixed voltage of the battery.



\*R<sub>S</sub>—sets output impedance of charger:  $Z_{OUT} = R_S \left(1 + \frac{R_2}{R_1}\right)$ 

Use of  $R_S$  allows low charging rates with fully charged battery.





# **Typical Applications (continued)**

# 9.2.15 Adjustable 4-A Regulator

Using three LM317-N devices in parallel increases load current capability (Figure 33). Output voltage is set by the variable resistor tied to the non-inverting terminal of the operational amplifier, and reference current to the transistor is developed across the 100  $\Omega$  resistor. When output voltage rises, the operational amplifier corrects by drawing current from the base, closing the transistor. This effectively pulls ADJ down and lowers the output voltage through negative feedback.

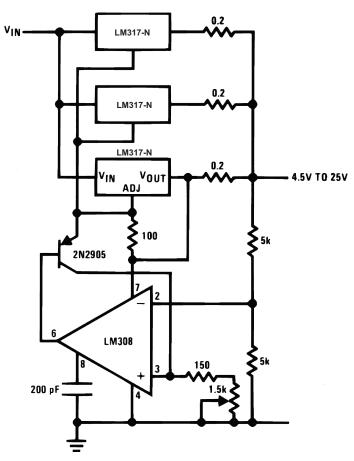


Figure 33. Adjustable 4-A Regulator

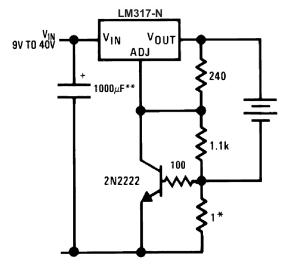
TEXAS INSTRUMENTS

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# **Typical Applications (continued)**

# 9.2.16 Current-Limited 6-V Charger

The current in a battery charger application is limited by switching between constant current and constant voltage states (see Figure 34). When the battery pulls low current, the drop across the 1  $\Omega$  resistor is not substantial and the NPN remains off. A constant voltage is seen across the battery, as regulated by the resistor divider. When current through the battery rises past peak current, the 1  $\Omega$  provides enough voltage to turn the transistor on, pulling ADJ close to ground. This results in limiting the maximum current to the battery.

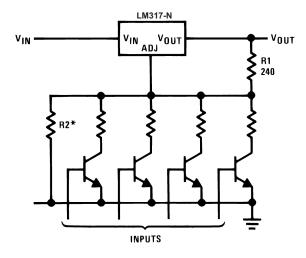


\*Sets peak current (0.6A for 1Ω) \*\*The 1000-μF is recommended to filter out input transients

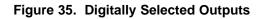
Figure 34. Current-Limited 6-V Charger

# 9.2.17 Digitally Selected Outputs

Figure 35 demonstrates a digitally selectable output voltage. In its default state, all transistors are off and the output voltage is set based on R1 and R2. By driving certain transistors, the associated resistor is connected in parallel to R2, modifying the output voltage of the regulator.



\*Sets maximum V<sub>OUT</sub>



$$V_{OUT} = V_{REF} \left( 1 + \frac{R2}{R1} \right) + I_{ADJ}R2$$

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(2)



# **10** Power Supply Recommendations

The input supply to the LM117 and LM317-N must be kept at a voltage level such that its maximum input to output differential voltage is not exceeded. The minimum dropout voltage must also be met with extra headroom when possible to keep the LM117 and LM317-N in regulation. An input capacitor is recommended, especially when the input pin is located more than 6 inches away from the power supply source. For more information regarding capacitor selection, refer to *External Capacitors*.

# 11 Layout

## 11.1 Layout Guidelines

Some layout guidelines must be followed to ensure proper regulation of the output voltage with minimum noise. Traces carrying the load current must be wide to reduce the amount of parasitic trace inductance and the feedback loop from  $V_{OUT}$  to ADJ must be kept as short as possible. To improve PSRR, a bypass capacitor can be placed at the ADJ pin and must be located as close as possible to the IC. In cases when  $V_{IN}$  shorts to ground, an external diode must be placed from  $V_{OUT}$  to  $V_{IN}$  to divert the surge current from the output capacitor and protect the IC. Similarly, in cases when a large bypass capacitor is placed at the ADJ pin and  $V_{OUT}$  shorts to ground, an external diode must be placed from ADJ to  $V_{OUT}$  to provide a path for the bypass capacitor to discharge. These diodes must be placed close to the corresponding IC pins to increase their effectiveness.

# 11.2 Layout Example

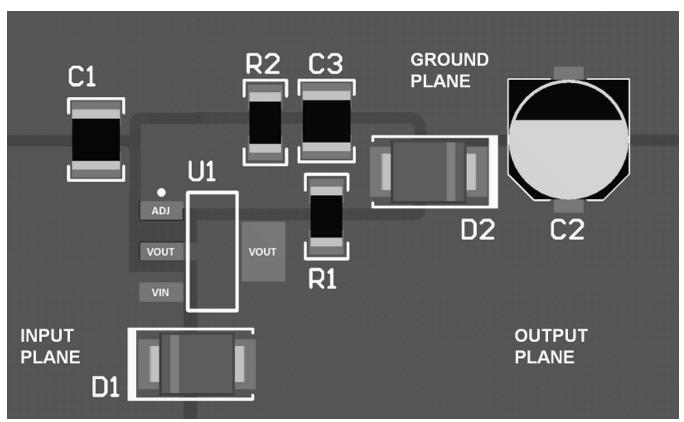


Figure 36. Layout Example (SOT-223)

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# Layout Example (continued)

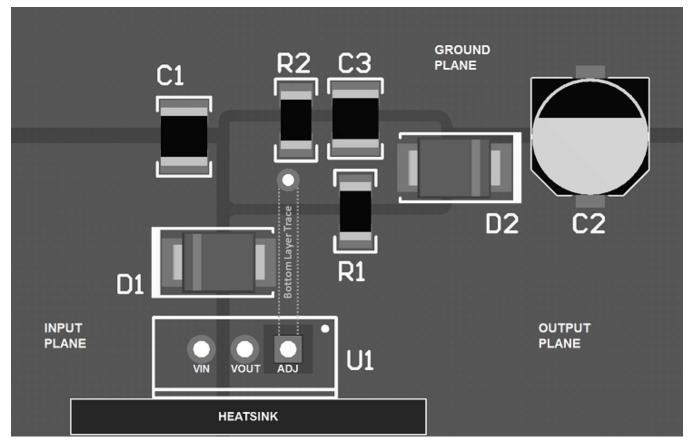


Figure 37. Layout Example (TO-220)

# **11.3 Thermal Considerations**

# 11.3.1 Heatsink Requirements

The LM317-N regulators have internal thermal shutdown to protect the device from over-heating. Under all operating conditions, the junction temperature of the LM317-N must not exceed the rated maximum junction temperature (T<sub>J</sub>) of 150°C for the LM117, or 125°C for the LM317-N. A heatsink may be required depending on the maximum device power dissipation and the maximum ambient temperature of the application. To determine if a heatsink is needed, the power dissipated by the regulator, P<sub>D</sub>, must be calculate with Equation 3:

$$\mathsf{P}_\mathsf{D} = ((\mathsf{V}_\mathsf{IN} - \mathsf{V}_\mathsf{OUT}) \times \mathsf{I}_\mathsf{L}) + (\mathsf{V}_\mathsf{IN} \times \mathsf{I}_\mathsf{G})$$

(3)

(4)

Figure 38 shows the voltage and currents which are present in the circuit.

The next parameter which must be calculated is the maximum allowable temperature rise, T<sub>R(MAX)</sub> in Equation 4:

$$T_{R(MAX)} = T_{J(MAX)} - T_{A(MAX)}$$

where  $T_{J(MAX)}$  is the maximum allowable junction temperature (150°C for the LM117, or 125°C for the LM317-N), and  $T_{A(MAX)}$  is the maximum ambient temperature that will be encountered in the application.

Using the calculated values for  $T_{R(MAX)}$  and  $P_D$ , the maximum allowable value for the junction-to-ambient thermal resistance ( $\theta_{JA}$ ) can be calculated with Equation 5:

$$\theta_{JA} = (T_{R(MAX)} / P_D)$$

(5)



# **Thermal Considerations (continued)**

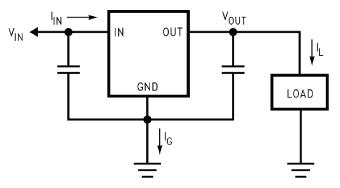


Figure 38. Power Dissipation Diagram

If the calculated maximum allowable thermal resistance is higher than the actual package rating, then no additional work is needed. If the calculated maximum allowable thermal resistance is lower than the actual package rating either the power dissipation (P<sub>D</sub>) needs to be reduced, the maximum ambient temperature T<sub>A(MAX)</sub> needs to be reduced, the thermal resistance ( $\theta_{JA}$ ) must be lowered by adding a heatsink, or some combination of these.

If a heatsink is needed, the value can be calculated from Equation 6:

$$\theta_{\mathsf{HA}} \leq (\theta_{\mathsf{JA}} - (\theta_{\mathsf{CH}} + \theta_{\mathsf{JC}}))$$

where

- $\theta_{CH}$  is the thermal resistance of the contact area between the device case and the heatsink surface
- $\theta_{JC}$  is thermal resistance from the junction of the die to surface of the package case

When a value for  $\theta_{HA}$  is found using the equation shown, a heatsink must be selected that has a value that is less than, or equal to, this number.

The  $\theta_{HA}$  rating is specified numerically by the heatsink manufacturer in the catalog, or shown in a curve that plots temperature rise vs power dissipation for the heatsink.

#### 11.3.2 Heatsinking Surface Mount Packages

The TO-263 (KTT), SOT-223 (DCY) and TO-252 (NDP) packages use a copper plane on the PCB and the PCB itself as a heatsink. To optimize the heat sinking ability of the plane and PCB, solder the tab of the package to the plane.

#### 11.3.2.1 Heatsinking the SOT-223 (DCY) Package

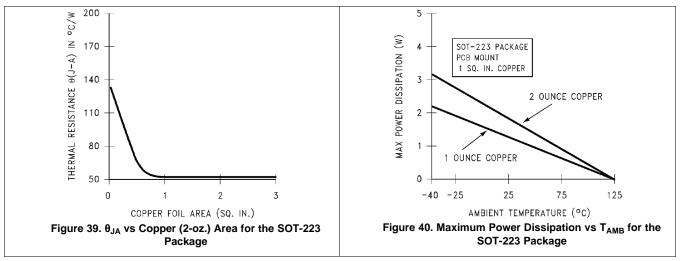
Figure 39 and Figure 40 show the information for the SOT-223 package. Figure 40 assumes a  $\theta_{JA}$  of 74°C/W for 1-oz. copper and 59.6°C/W for 2-oz. copper and a maximum junction temperature of 125°C. See AN-1028 (SNVA036) for thermal enhancement techniques to be used with SOT-223 and TO-252 packages.

(6)

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# **Thermal Considerations (continued)**



# 11.3.2.2 Heatsinking the TO-263 (KTT) Package

Figure 41 shows for the TO-263 the measured values of  $\theta_{JA}$  for different copper area sizes using a typical PCB with 1-oz. copper and no solder mask over the copper area used for heatsinking.

As shown in Figure 41, increasing the copper area beyond 1 square inch produces very little improvement. It must also be observed that the minimum value of  $\theta_{JA}$  for the TO-263 package mounted to a PCB is 32°C/W.

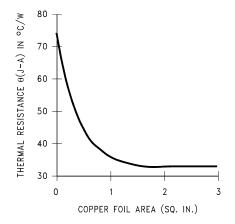


Figure 41.  $\theta_{JA}$  vs Copper (1-oz.) Area for the TO-263 Package

As a design aid, Figure 42 shows the maximum allowable power dissipation compared to ambient temperature for the TO-263 device (assuming  $\theta_{JA}$  is 35°C/W and the maximum junction temperature is 125°C).





# **Thermal Considerations (continued)**

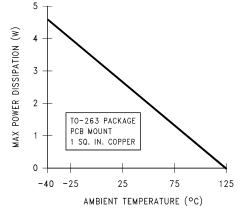


Figure 42. Maximum Power Dissipation vs T<sub>AMB</sub> for the TO-263 Package

# 11.3.2.3 Heatsinking the TO-252 (NDP) Package

If the maximum allowable value for  $\theta_{JA}$  is found to be  $\geq 54^{\circ}$ C/W (typical rated value) for the TO-252 package, no heatsink is needed because the package alone will dissipate enough heat to satisfy these requirements. If the calculated value for  $\theta_{JA}$  falls below these limits, a heatsink is required.

As a design aid, Table 2 shows the value of the  $\theta_{JA}$  of NDP the package for different heatsink area. The copper patterns that we used to measure these  $\theta_{JA}$ s are shown in Figure 47. Figure 43 reflects the same test results as what are in Table 2.

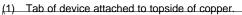
Figure 44 shows the maximum allowable power dissipation versus ambient temperature for the TO-252 device. Figure 45 shows the maximum allowable power dissipation versus copper area (in<sup>2</sup>) for the TO-252 device. See AN-1028 (SNVA036) for thermal enhancement techniques to be used with SOT-223 and TO-252 packages.

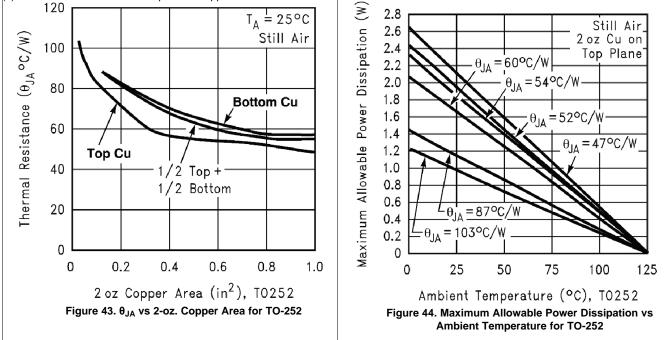


# **Thermal Considerations (continued)**

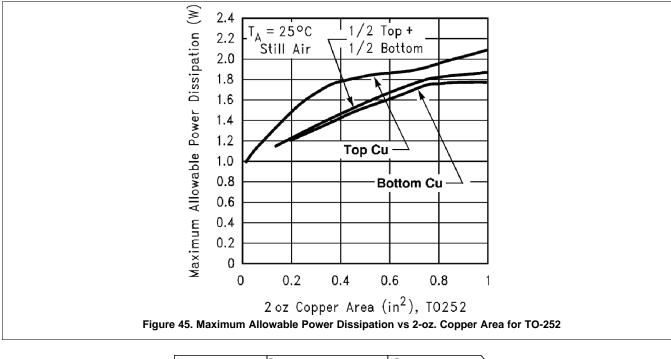
# Table 2. $\theta_{JA}$ Different Heatsink Area

LAYOUT COPPER AREA THERMAL RESISTANCE								
LAYOUT		THERMAL RESISTANCE						
	Top Side (in <sup>2</sup> ) <sup>(1)</sup>	Bottom Side (in <sup>2</sup> )	(θ <sub>JA</sub> °C/W) TO-252					
1	0.0123	0	103					
2	0.066	0	87					
3	0.3	0	60					
4	0.53	0	54					
5	0.76	0	52					
6	1.0	0	47					
7	0.066	0.2	84					
8	0.066	0.4	70					
9	0.066	0.6	63					
10	0.066	0.8	57					
11	0.066	1.0	57					
12	0.066	0.066	89					
13	0.175	0.175	72					
14	0.284	0.284	61					
15	0.392	0.392	55					
16	0.5	0.5	53					









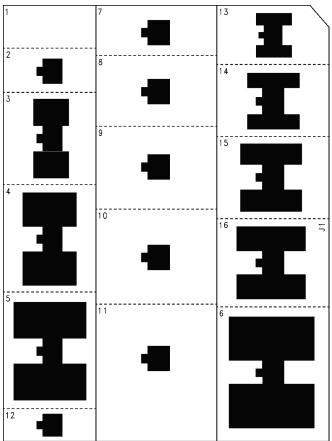


Figure 46. Top View of the Thermal Test Pattern in Actual Scale



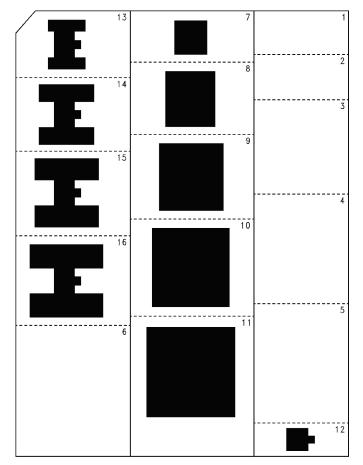


Figure 47. Bottom View of the Thermal Test Pattern in Actual Scale



# **12 Device and Documentation Support**

# **12.1** Documentation Support

#### 12.1.1 Related Documentation

- For applications requiring greater output current, see LM150 series (3A) (SNVS772) and LM138 series (5A) (SNVS771) data sheets.
- For the negative complement, see LM137 (SNVS778) series data sheet.
- For specifications and availability for military and space grades of LM117/883, see the LM117QML data sheet (SNVS356).
- Specifications and availability for military and space grades of LM117JAN can be found in the LM117 data sheet (SNVS365).
- For thermal enhancement techniques to be used with SOT-223 and TO-252 packages, see AN-1028, Maximum Power Enhancement Techniques for Power Packages (SNVA036).

## 12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
LM117	Click here	Click here	Click here	Click here	Click here
LM317-N	Click here	Click here	Click here	Click here	Click here

#### Table 3. Related Links

# 12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E<sup>™</sup> Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help

solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

# 12.4 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

# 12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# 12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

# 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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23-Nov-2019

# **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty		Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)				-	(2)	(6)	(3)		(4/5)	
LM117H	ACTIVE	то	NDT	3	500	Green (RoHS & no Sb/Br)	AU	Level-1-NA-UNLIM	-55 to 150	( LM117HP+, LM117H P+)	Samples
LM117H/NOPB	ACTIVE	то	NDT	3	500	Green (RoHS & no Sb/Br)	AU	Level-1-NA-UNLIM	-55 to 150	( LM117HP+, LM117H P+)	Samples
LM117K	ACTIVE	TO-3	NDS	2	50	TBD	Call TI	Call TI	-55 to 125	LM117K STEELP+	Samples
LM117K STEEL	ACTIVE	TO-3	NDS	2	50	TBD	Call TI	Call TI	-55 to 150	LM117K STEELP+	Samples
LM117K STEEL/NOPB	ACTIVE	TO-3	NDS	2	50	Green (RoHS & no Sb/Br)	Call TI	Level-1-NA-UNLIM	-55 to 150	LM117K STEELP+	Samples
LM317EMP	NRND	SOT-223	DCY	4	1000	TBD	Call TI	Call TI	0 to 125	N01A	
LM317EMP/NOPB	ACTIVE	SOT-223	DCY	4	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 125	N01A	Samples
LM317EMPX/NOPB	ACTIVE	SOT-223	DCY	4	2000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	0 to 125	N01A	Samples
LM317H	ACTIVE	то	NDT	3	500	Green (RoHS & no Sb/Br)	AU	Level-1-NA-UNLIM	0 to 0	( LM317HP+, LM317H P+)	Samples
LM317H/NOPB	ACTIVE	то	NDT	3	500	Green (RoHS & no Sb/Br)	AU	Level-1-NA-UNLIM	0 to 0	( LM317HP+, LM317H P+)	Samples
LM317MDT/NOPB	ACTIVE	TO-252	NDP	3	75	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	LM317 MDT	Samples
LM317MDTX/NOPB	ACTIVE	TO-252	NDP	3	2500	Green (RoHS & no Sb/Br)	CU SN	Level-2-260C-1 YEAR	0 to 125	LM317 MDT	Samples
LM317S/NOPB	ACTIVE	DDPAK/ TO-263	КТТ	3	45	Pb-Free (RoHS Exempt)	CU SN	Level-3-245C-168 HR	0 to 125	LM317S P+	Samples
LM317SX/NOPB	ACTIVE	DDPAK/ TO-263	КТТ	3	500	Pb-Free (RoHS Exempt)	CU SN	Level-3-245C-168 HR	0 to 125	LM317S P+	Samples
LM317T	NRND	TO-220	NDE	3	45	TBD	Call TI	Call TI		LM317T P+	
LM317T/LF01	ACTIVE	TO-220	NDG	3	45	Pb-Free (RoHS Exempt)	CU SN	Level-4-260C-72 HR		LM317T P+	Samples
LM317T/NOPB	ACTIVE	TO-220	NDE	3	45	Green (RoHS & no Sb/Br)	CU SN	Level-1-NA-UNLIM	0 to 125	LM317T P+	Samples

<sup>(1)</sup> The marketing status values are defined as follows:



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ACTIVE: Product device recommended for new designs. LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design. PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption. **Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(<sup>5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



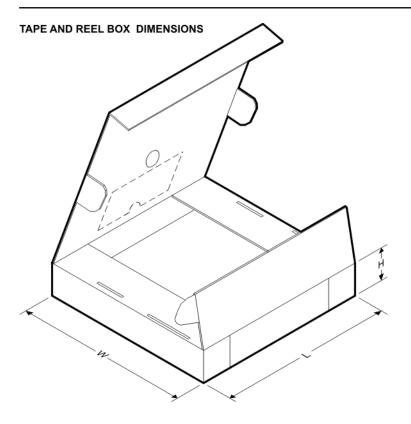
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM317EMP	SOT-223	DCY	4	1000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LM317EMP/NOPB	SOT-223	DCY	4	1000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LM317EMPX/NOPB	SOT-223	DCY	4	2000	330.0	16.4	7.0	7.5	2.2	12.0	16.0	Q3
LM317MDTX/NOPB	TO-252	NDP	3	2500	330.0	16.4	6.9	10.5	2.7	8.0	16.0	Q2
LM317SX/NOPB	DDPAK/ TO-263	КТТ	3	500	330.0	24.4	10.75	14.85	5.0	16.0	24.0	Q2

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

24-Dec-2019

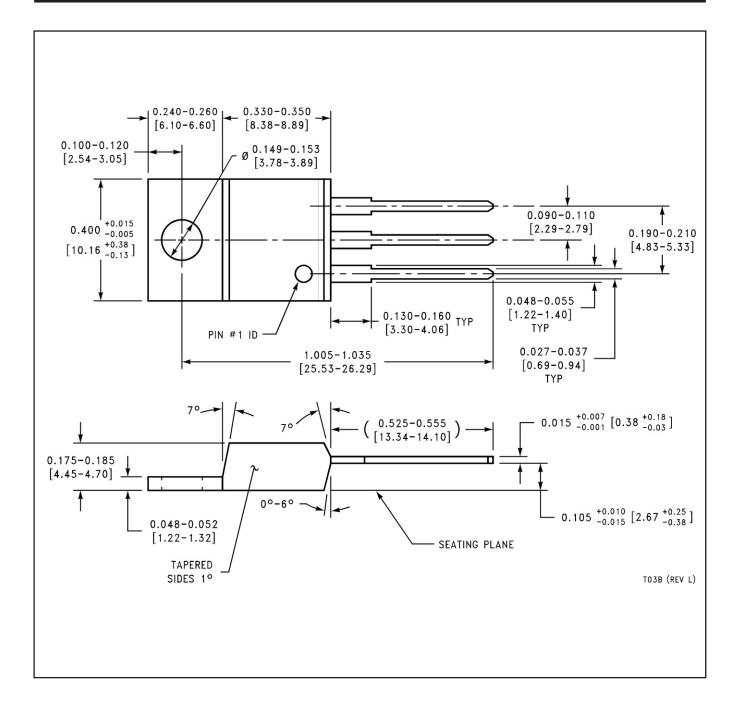


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
LM317EMP	SOT-223	DCY	4	1000	367.0	367.0	35.0	
LM317EMP/NOPB	SOT-223	DCY	4	1000	367.0	367.0	35.0	
LM317EMPX/NOPB	SOT-223	DCY	4	2000	367.0	367.0	35.0	
LM317MDTX/NOPB	TO-252	NDP	3	2500	367.0	367.0	38.0	
LM317SX/NOPB	DDPAK/TO-263	КТТ	3	500	367.0	367.0	45.0	

### **MECHANICAL DATA**

# NDE0003B





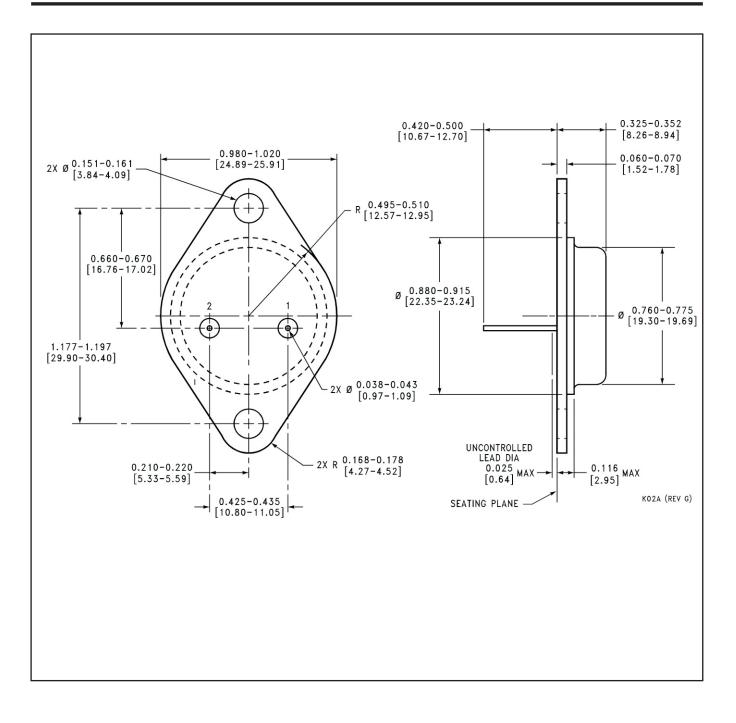
### **MECHANICAL DATA**

# KTT0003B





# NDS0002A





#### **MECHANICAL DATA**

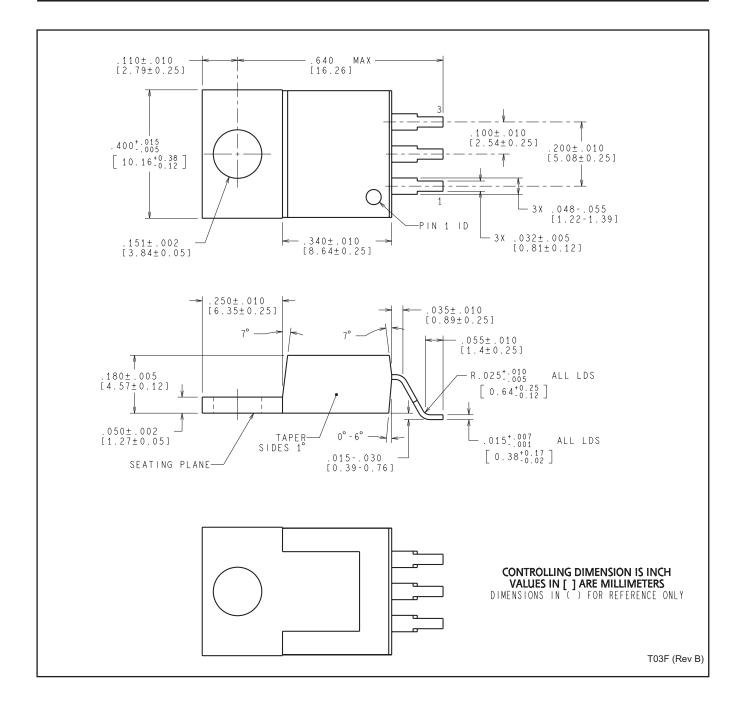
MPDS094A - APRIL 2001 - REVISED JUNE 2002



- B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion.
  - D. Falls within JEDEC TO-261 Variation AA.



# NDG0003F





# **NDP0003B**



# **PACKAGE OUTLINE**

#### TO-252 - 2.55 mm max height

TRANSISTOR OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  This drawing is subject to change without notice.
  Reference JEDEC registration TO-252.

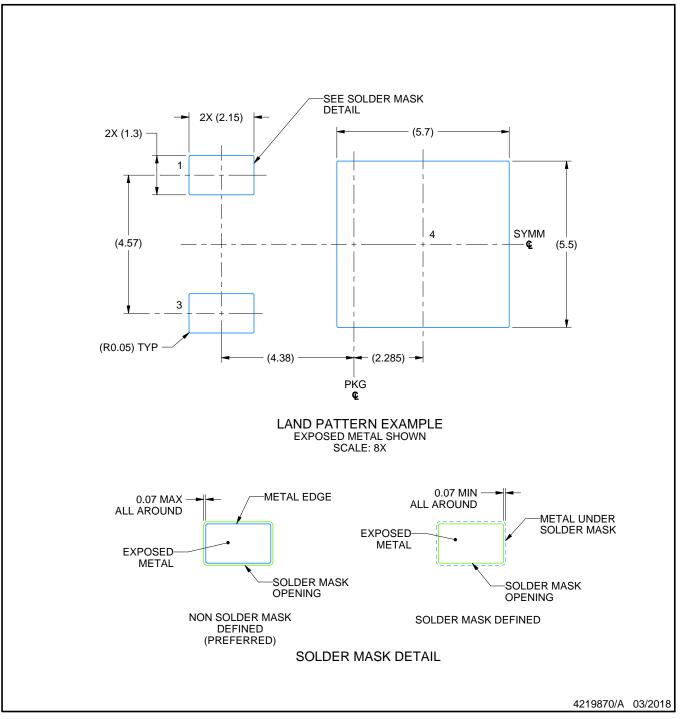


### NDP0003B

# **EXAMPLE BOARD LAYOUT**

#### TO-252 - 2.55 mm max height

TRANSISTOR OUTLINE



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature numbers SLMA002(www.ti.com/lit/slm002) and SLMA004 (www.ti.com/lit/slma004).

5. Vias are optional depending on application, refer to device data sheet. It is recommended that vias under paste be filled, plugged or tented.

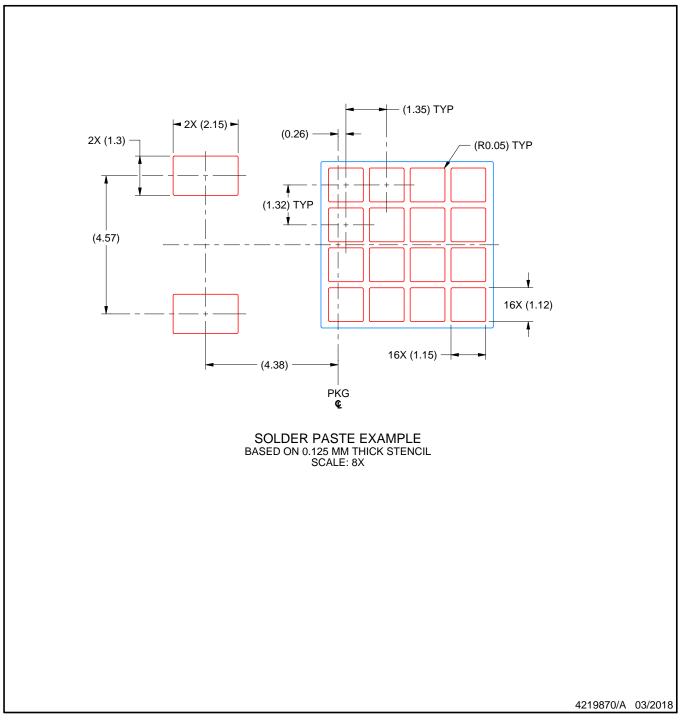


# **NDP0003B**

# **EXAMPLE STENCIL DESIGN**

#### TO-252 - 2.55 mm max height

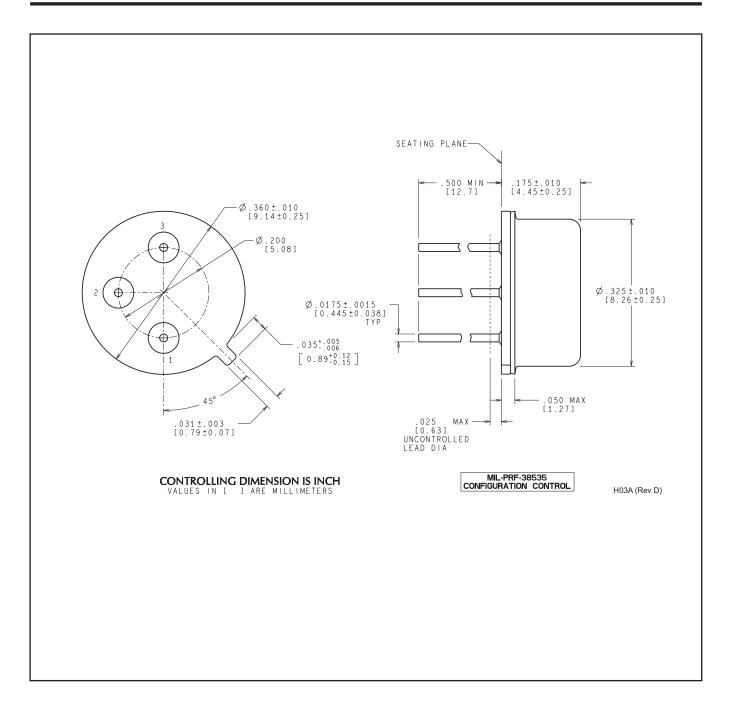
TRANSISTOR OUTLINE



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.7. Board assembly site may have different recommendations for stencil design.







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